

# NCV8774

## Ultra Low $I_q$ 350 mA LDO Regulator

The NCV8774 is a 350 mA LDO regulator. Its robustness allows NCV8774 to be used in severe automotive environments. Ultra low quiescent current as low as 18  $\mu$ A typical makes it suitable for applications permanently connected to battery requiring ultra low quiescent current with or without load. This feature is especially critical when modules remain in active mode when ignition is off. The NCV8774 contains protection functions as current limit, thermal shutdown and reverse output current protection.

### Features

- Output Voltage Options: 3.3 V and 5 V
- Output Voltage Accuracy:  $\pm 1.5\%$  ( $T_J = 25^\circ\text{C}$  to  $125^\circ\text{C}$ )
- Output Current up to 350 mA
- Ultra Low Quiescent Current: typ 18  $\mu$ A (max 23  $\mu$ A)
- Very Wide Range of  $C_{out}$  and ESR Values for Stability
- Wide Input Voltage Operation Range: up to 40 V
- Protection Features
  - Current Limitation
  - Thermal Shutdown
- These are Pb-Free Devices

### Typical Applications

- Body Control Module
- Instruments and Clusters
- Occupant Protection and Comfort
- Powertrain

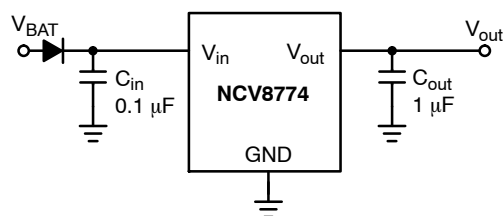


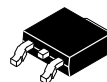
Figure 1. Typical Application Schematic



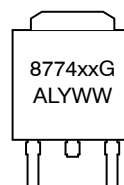
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### MARKING DIAGRAM



**DPAK-3  
DT SUFFIX  
CASE 369C**



|       |                     |
|-------|---------------------|
| xx    | = Voltage Option    |
| A     | = Assembly Location |
| WL, L | = Wafer Lot         |
| Y     | = Year              |
| WW    | = Work Week         |
| G     | = Pb-Free Package   |

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

# NCV8774

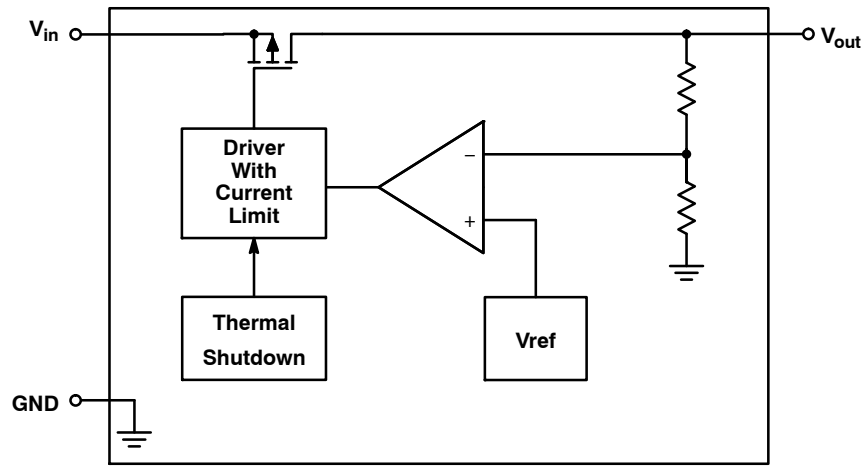


Figure 2. Simplified Block Diagram

## PIN CONNECTIONS

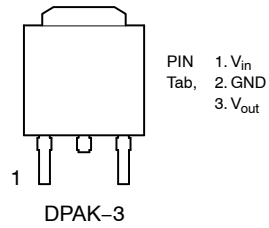


Figure 3. Pin Connections

## PIN FUNCTION DESCRIPTION

| Pin No. | Pin Name  | Description                                                                              |
|---------|-----------|------------------------------------------------------------------------------------------|
| 1       | $V_{in}$  | Positive Power Supply Input. Connect 0.1 $\mu$ F capacitor to ground.                    |
| 2, TAB  | GND       | Power Supply Ground.                                                                     |
| 3       | $V_{out}$ | Regulated Output Voltage. Connect 1 $\mu$ F capacitor with ESR < 100 $\Omega$ to ground. |

# ABSOLUTE MAXIMUM RATINGS

| Rating                                                  | Symbol    | Min       | Max             | Unit |
|---------------------------------------------------------|-----------|-----------|-----------------|------|
| Input Voltage (Note 1)<br>DC<br>Transient, $t < 100$ ms | $V_{in}$  | -0.3<br>– | 40<br>45        | V    |
| Input Current                                           | $I_{in}$  | –5        | –               | mA   |
| Output Voltage (Note 2)                                 | $V_{out}$ | –0.3      | 5.5             | V    |
| Output Current                                          | $I_{out}$ | –3        | Current Limited | mA   |
| Junction Temperature                                    | $T_J$     | –40       | 150             | °C   |
| Storage Temperature                                     | $T_{STG}$ | –55       | 150             | °C   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
2. 5.5 V or ( $V_{in} + 0.3$  V) (whichever is lower).

# ESD CAPABILITY (Note 3)

| Rating                               | Symbol      | Min  | Max | Unit |
|--------------------------------------|-------------|------|-----|------|
| ESD Capability, Human Body Model     | $ESD_{HBM}$ | –2   | 2   | kV   |
| ESD Capability, Machine Model        | $ESD_{MM}$  | –200 | 200 | V    |
| ESD Capability, Charged Device Model | $ESD_{CDM}$ | –1   | 1   | kV   |

3. This device series incorporates ESD protection and is tested by the following methods:  
ESD Human Body Model tested per AEC-Q100-002 (JS-001-2010)  
ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)  
ESD Charge Device Model tested per AEC-Q100-011 (EIA/JESD22-C101)

# LEAD SOLDERING TEMPERATURE AND MSL (Note 4)

| Rating                                                                   | Symbol    | Min | Max      | Unit |
|--------------------------------------------------------------------------|-----------|-----|----------|------|
| Moisture Sensitivity Level<br>DPAK-3                                     | MSL       | 1   |          | –    |
| Lead Temperature Soldering<br>Reflow (SMD Styles Only), Pb-Free Versions | $T_{SLD}$ | –   | 265 peak | °C   |

4. For more information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# THERMAL CHARACTERISTICS (Note 5)

| Rating                                                                                                                          | Symbol                           | Value     | Unit |
|---------------------------------------------------------------------------------------------------------------------------------|----------------------------------|-----------|------|
| Thermal Characteristics, DPAK-3<br>Thermal Resistance, Junction-to-Air (Note 6)<br>Thermal Reference, Junction-to-Case (Note 6) | $R_{\theta JA}$<br>$R_{\psi JC}$ | 56<br>8.4 | °C/W |

5. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
6. Values based on copper area of 645 mm<sup>2</sup> (or 1 in<sup>2</sup>) of 1 oz copper thickness and FR4 PCB substrate.

# RECOMMENDED OPERATING RANGE (Note 7)

| Rating                 | Symbol   | Min | Max | Unit |
|------------------------|----------|-----|-----|------|
| Input Voltage (Note 8) | $V_{in}$ | 4.5 | 40  | V    |
| Junction Temperature   | $T_J$    | –40 | 150 | °C   |

7. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
8. Minimum  $V_{in} = 4.5$  V or ( $V_{out} + V_{DO}$ ), whichever is higher.

**ELECTRICAL CHARACTERISTICS**  $V_{in} = 13.2\text{ V}$ ,  $C_{in} = 0.1\text{ }\mu\text{F}$ ,  $C_{out} = 1\text{ }\mu\text{F}$ , for typical values  $T_J = 25^\circ\text{C}$ , for min/max values  $T_J = -40^\circ\text{C}$  to  $150^\circ\text{C}$ ; unless otherwise noted. (Notes 9 and 10)

| Parameter                                     | Test Conditions                                                                                                                                                                                                                                                                                                                                                            | Symbol              | Min                                    | Typ                      | Max                                   | Unit |
|-----------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------|----------------------------------------|--------------------------|---------------------------------------|------|
| <b>REGULATOR OUTPUT</b>                       |                                                                                                                                                                                                                                                                                                                                                                            |                     |                                        |                          |                                       |      |
| Output Voltage (Accuracy %)<br>3.3 V<br>5.0 V | $T_J = 25^\circ\text{C}$ to $125^\circ\text{C}$<br>$V_{in} = 4.5\text{ V}$ to $16\text{ V}$ , $I_{out} = 0.1\text{ mA}$ to $200\text{ mA}$<br>$V_{in} = 5.575\text{ V}$ to $16\text{ V}$ , $I_{out} = 0.1\text{ mA}$ to $200\text{ mA}$                                                                                                                                    | $V_{out}$           | 3.2505<br>4.925<br>(-1.5 %)            | 3.3<br>5.0               | 3.3495<br>5.075<br>(+1.5%)            | V    |
| Output Voltage (Accuracy %)<br>3.3 V<br>5.0 V | $V_{in} = 4.5\text{ V}$ to $40\text{ V}$ , $I_{out} = 0.1\text{ mA}$ to $200\text{ mA}$<br>$V_{in} = 4.5\text{ V}$ to $16\text{ V}$ , $I_{out} = 0.1\text{ mA}$ to $350\text{ mA}$<br>$V_{in} = 5.6\text{ V}$ to $40\text{ V}$ , $I_{out} = 0.1\text{ mA}$ to $200\text{ mA}$<br>$V_{in} = 5.975\text{ V}$ to $16\text{ V}$ , $I_{out} = 0.1\text{ mA}$ to $350\text{ mA}$ | $V_{out}$           | 3.234<br>3.234<br>4.9<br>4.9<br>(-2 %) | 3.3<br>3.3<br>5.0<br>5.0 | 3.366<br>3.366<br>5.1<br>5.1<br>(+2%) | V    |
| Output Voltage (Accuracy %)<br>3.3 V<br>5.0 V | $T_J = -40^\circ\text{C}$ to $125^\circ\text{C}$<br>$V_{in} = 4.5\text{ V}$ to $28\text{ V}$ , $I_{out} = 0\text{ mA}$ to $350\text{ mA}$<br>$V_{in} = 5.975\text{ V}$ to $28\text{ V}$ , $I_{out} = 0\text{ mA}$ to $350\text{ mA}$                                                                                                                                       | $V_{out}$           | 3.234<br>4.9<br>(-2 %)                 | 3.3<br>5.0               | 3.366<br>5.1<br>(+2%)                 | V    |
| Line Regulation<br>3.3 V<br>5.0 V             | $V_{in} = 4.5\text{ V}$ to $28\text{ V}$ , $I_{out} = 5\text{ mA}$<br>$V_{in} = 6\text{ V}$ to $28\text{ V}$ , $I_{out} = 5\text{ mA}$                                                                                                                                                                                                                                     | $\text{Reg}_{line}$ | -20                                    | 0                        | 20                                    | mV   |
| Load Regulation                               | $I_{out} = 0.1\text{ mA}$ to $350\text{ mA}$                                                                                                                                                                                                                                                                                                                               | $\text{Reg}_{load}$ | -35                                    | 0                        | 35                                    | mV   |
| Dropout Voltage (Note 11)<br>5.0 V            | $I_{out} = 200\text{ mA}$<br>$I_{out} = 350\text{ mA}$                                                                                                                                                                                                                                                                                                                     | $V_{DO}$            | -<br>-                                 | 250<br>440               | 500<br>875                            | mV   |

**QUIESCENT CURRENT**

|                                                |                                                                                                                                     |       |        |         |          |               |
|------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|-------|--------|---------|----------|---------------|
| Quiescent Current ( $I_q = I_{in} - I_{out}$ ) | $I_{out} = 0.1\text{ mA}$ , $T_J = 25^\circ\text{C}$<br>$I_{out} = 0.1\text{ mA}$ to $350\text{ mA}$ , $T_J \leq 125^\circ\text{C}$ | $I_q$ | -<br>- | 18<br>- | 22<br>23 | $\mu\text{A}$ |
|------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|-------|--------|---------|----------|---------------|

**CURRENT LIMIT PROTECTION**

|                             |                                      |           |     |   |      |    |
|-----------------------------|--------------------------------------|-----------|-----|---|------|----|
| Current Limit               | $V_{out} = 0.96 \times V_{out\_nom}$ | $I_{LIM}$ | 400 | - | 1100 | mA |
| Short Circuit Current Limit | $V_{out} = 0\text{ V}$               | $I_{SC}$  | 400 | - | 1100 | mA |

**PSRR**

|                                         |                                           |      |   |    |   |    |
|-----------------------------------------|-------------------------------------------|------|---|----|---|----|
| Power Supply Ripple Rejection (Note 12) | $f = 100\text{ Hz}$ , $0.5\text{ V}_{pp}$ | PSRR | - | 54 | - | dB |
|-----------------------------------------|-------------------------------------------|------|---|----|---|----|

**THERMAL SHUTDOWN**

|                                        |  |          |     |     |     |                  |
|----------------------------------------|--|----------|-----|-----|-----|------------------|
| Thermal Shutdown Temperature (Note 12) |  | $T_{SD}$ | 150 | 175 | 195 | $^\circ\text{C}$ |
| Thermal Shutdown Hysteresis (Note 12)  |  | $T_{SH}$ | -   | 25  | -   | $^\circ\text{C}$ |

9. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

10. Performance guaranteed over the indicated operating temperature range by design and/or characterization tested at  $T_A \approx T_J$ . Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

11. Measured when output voltage falls 100 mV below the regulated voltage at  $V_{in} = 13.2\text{ V}$ .

12. Values based on design and/or characterization.

TYPICAL CHARACTERISTICS

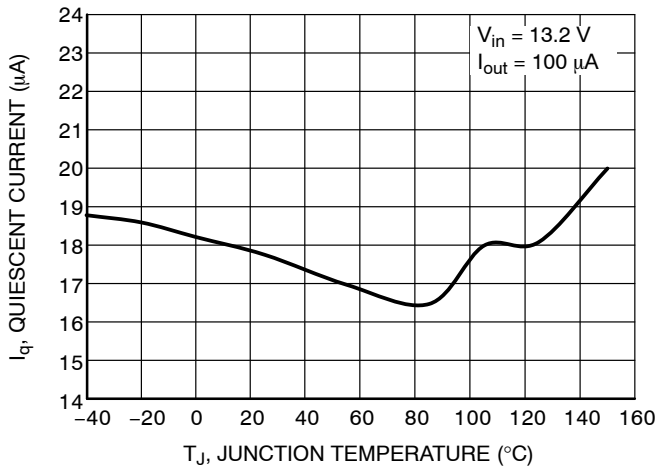


Figure 4. Quiescent Current vs. Temperature

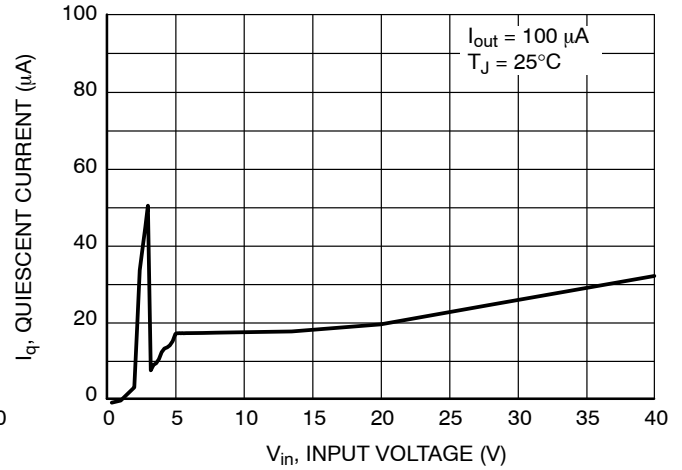


Figure 5. Quiescent Current vs. Input Voltage

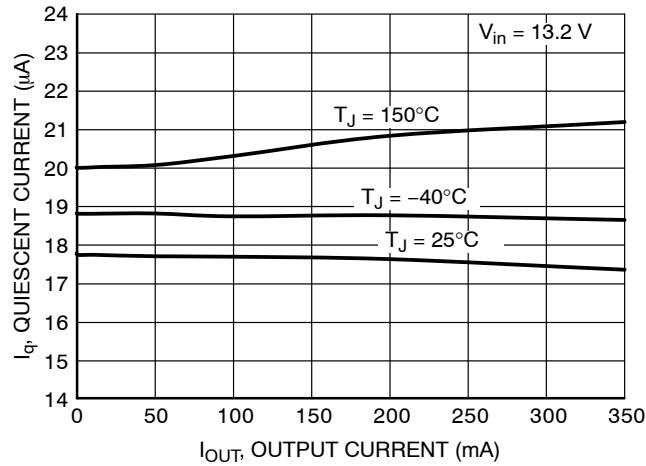


Figure 6. Quiescent Current vs. Output Current

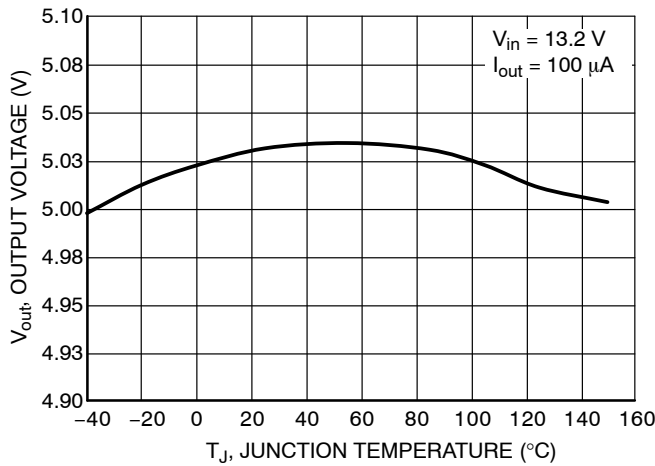


Figure 7. Output Voltage vs. Temperature  
(5 V Option)

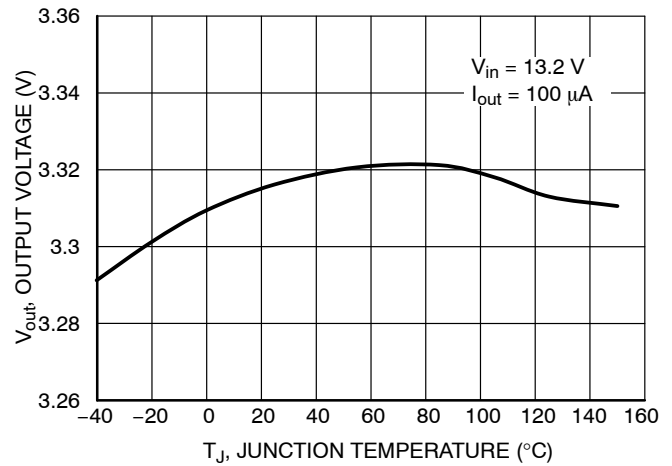


Figure 8. Output Voltage vs. Temperature  
(3.3 V Option)

TYPICAL CHARACTERISTICS

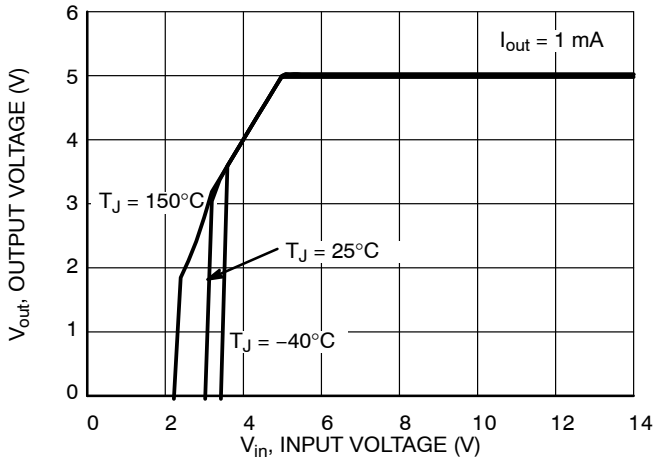


Figure 9. Output Voltage vs. Input Voltage  
(5 V Option)

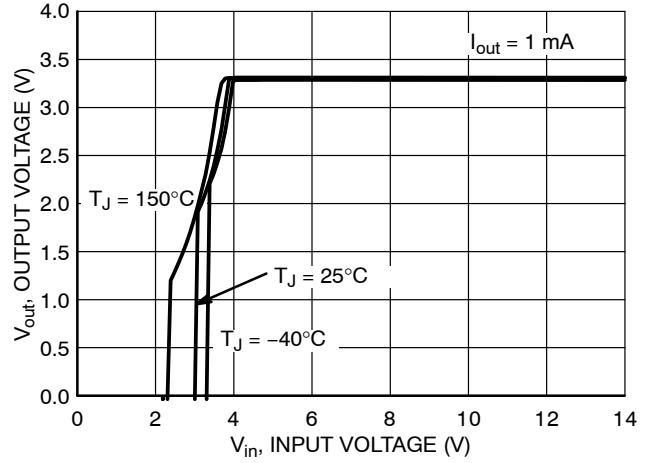


Figure 10. Output Voltage vs. Input Voltage  
(3.3 V Option)

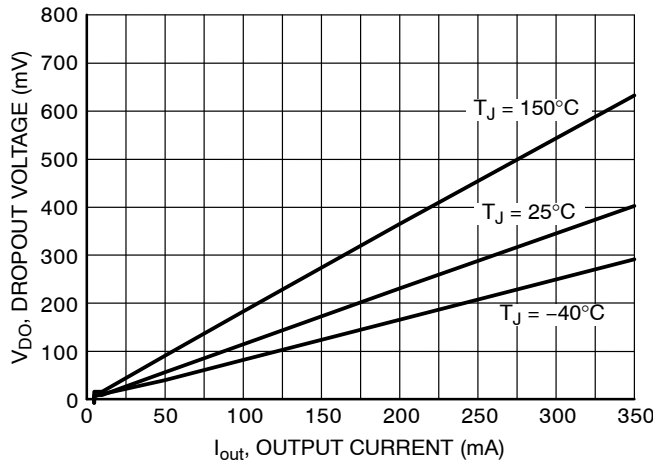


Figure 11. Dropout vs. Output Current  
(5 V Option)

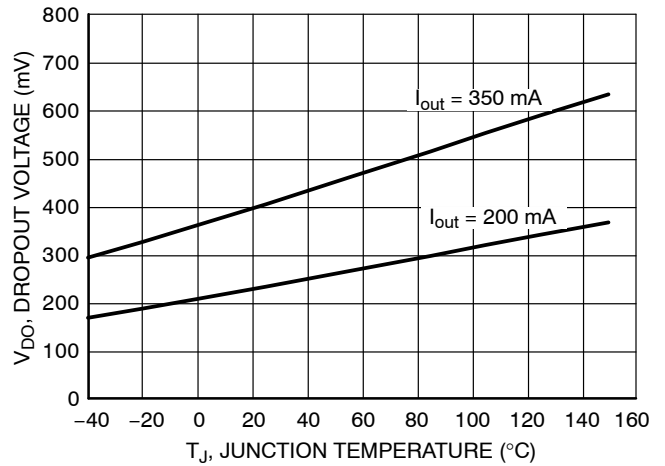


Figure 12. Dropout vs. Temperature  
(5 V Option)

TYPICAL CHARACTERISTICS

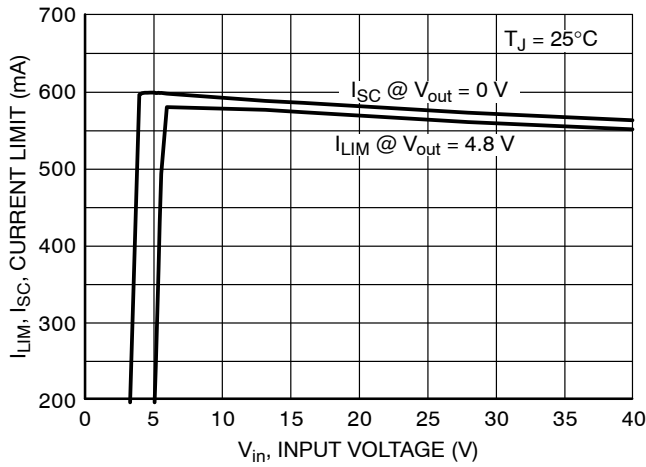


Figure 13. Output Current Limit vs. Input Voltage (5 V Option)

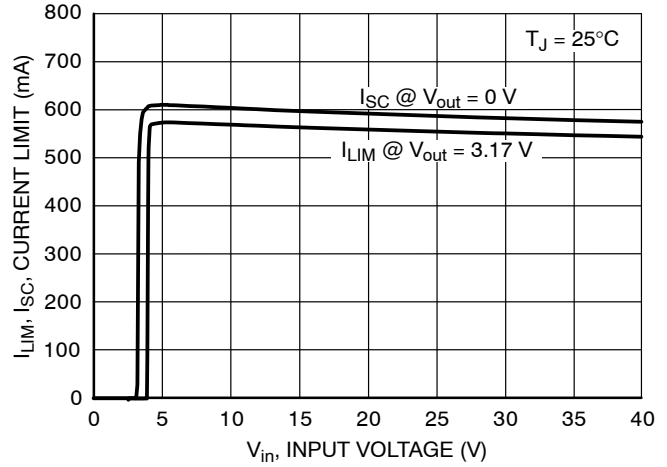


Figure 14. Output Current Limit vs. Input Voltage (3.3 V Option)

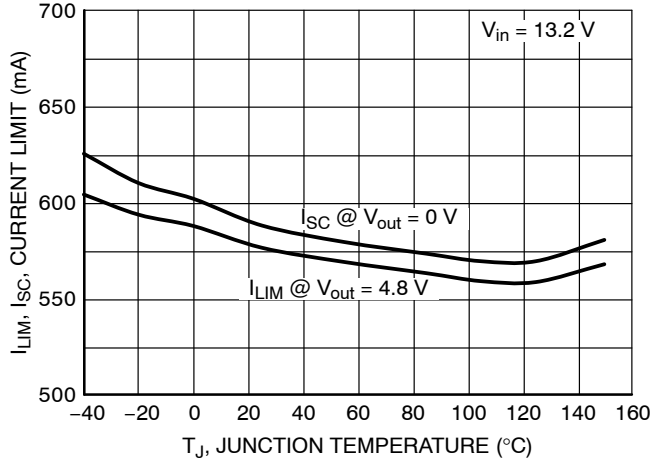


Figure 15. Output Current Limit vs. Temperature (5 V Option)

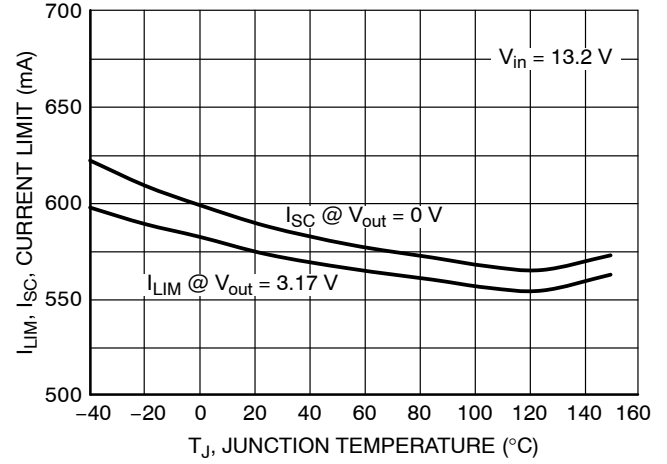


Figure 16. Output Current Limit vs. Temperature (3.3 V Option)

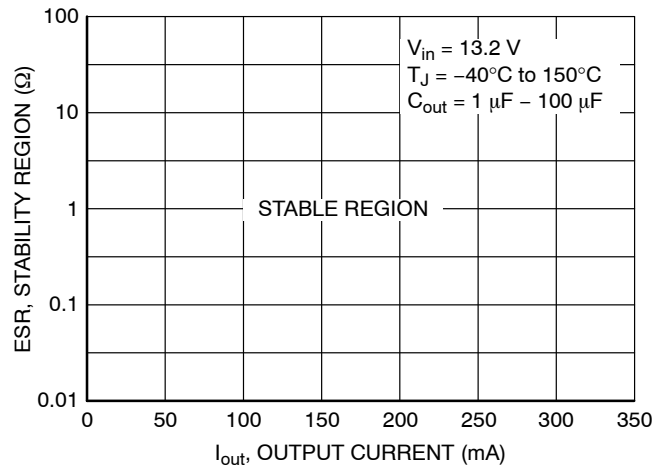


Figure 17.  $C_{out}$  ESR Stability Region vs. Output Current

TYPICAL CHARACTERISTICS

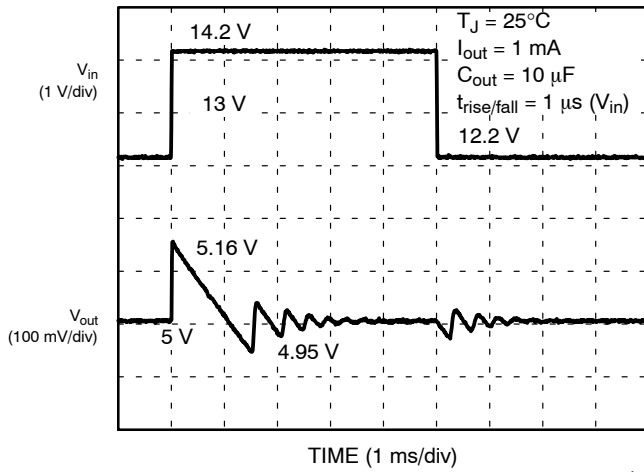


Figure 18. Line Transients  
(5 V Option)

14.2 V

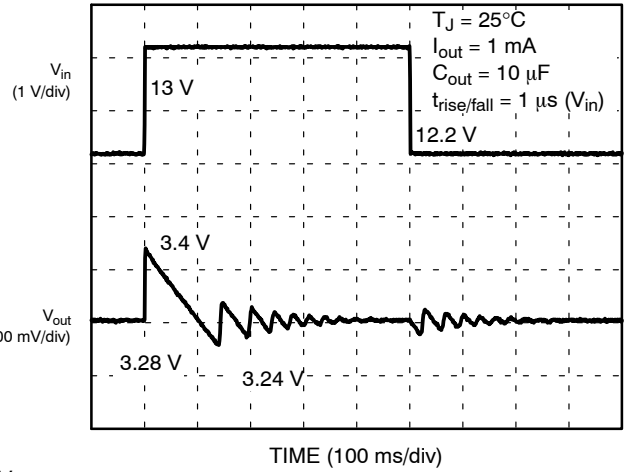


Figure 19. Line Transients  
(3.3 V Option)

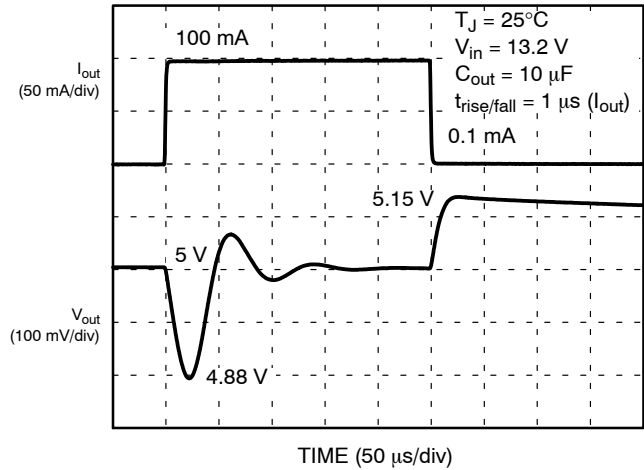


Figure 20. Load Transients  
(5 V Option)

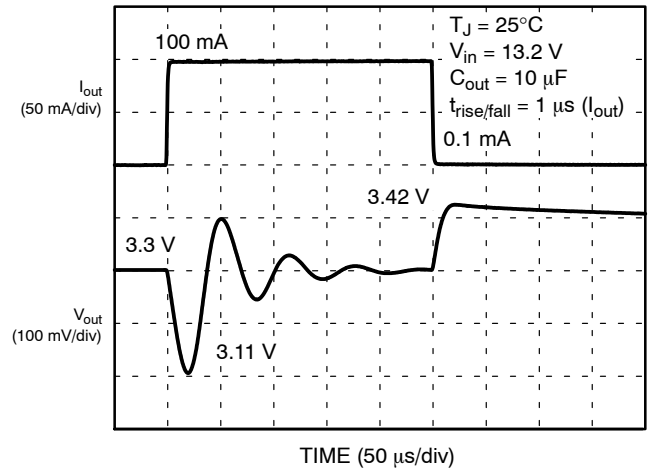


Figure 21. Load Transients  
(3.3 V Option)

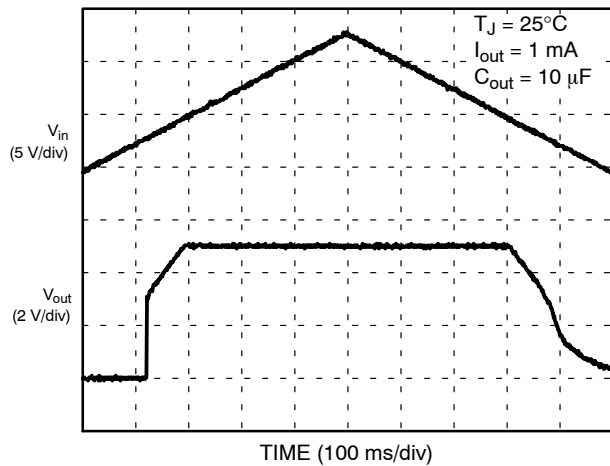


Figure 22. Power Up/Down Response  
(5 V Option)

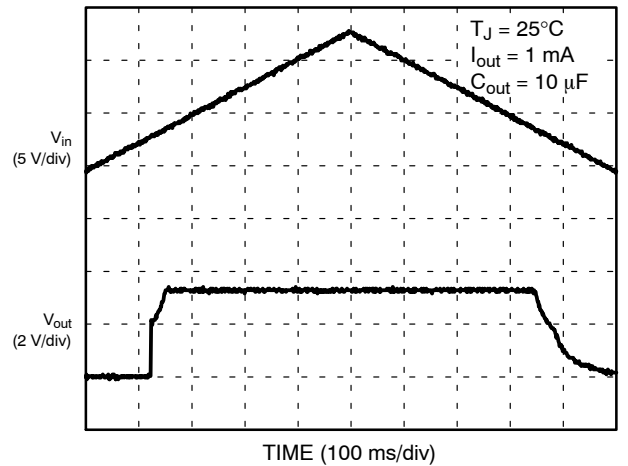


Figure 23. Power Up/Down Response  
(3.3 V Option)

TYPICAL CHARACTERISTICS

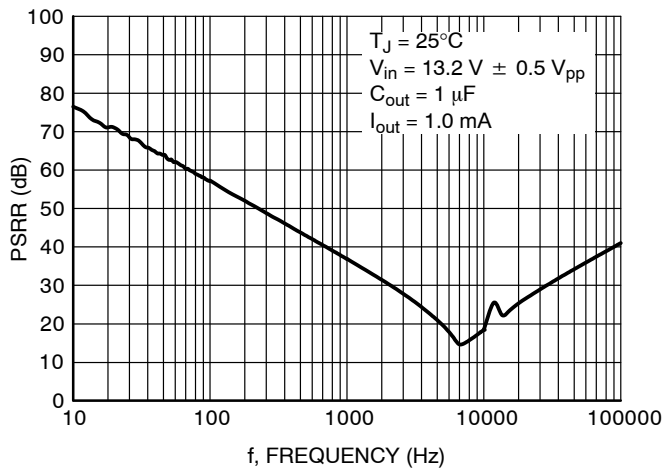


Figure 24. PSRR vs. Frequency  
(5 V Option)

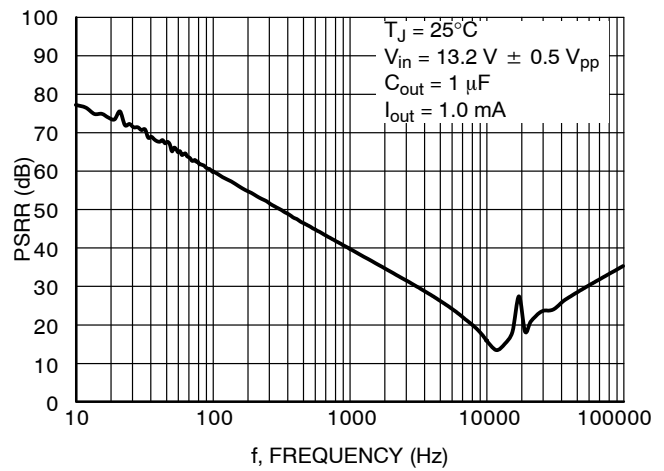


Figure 25. PSRR vs. Frequency  
(3.3 V Option)

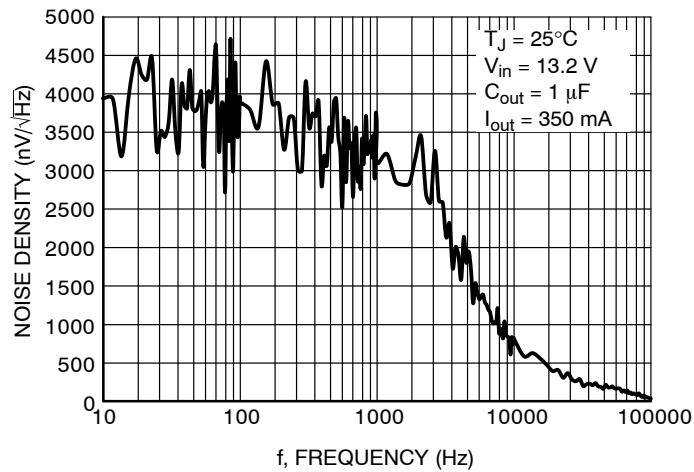


Figure 26. Noise vs. Frequency

## DEFINITIONS

**General**

All measurements are performed using short pulse low duty cycle techniques to maintain junction temperature as close as possible to ambient temperature.

**Output voltage**

The output voltage parameter is defined for specific temperature, input voltage and output current values or specified over Line, Load and Temperature ranges.

**Line Regulation**

The change in output voltage for a change in input voltage measured for specific output current over operating ambient temperature range.

**Load Regulation**

The change in output voltage for a change in output current measured for specific input voltage over operating ambient temperature range.

**Dropout Voltage**

The input to output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. It is measured when the output drops 100 mV below its nominal value. The junction temperature, load current, and minimum input supply requirements affect the dropout level.

**Quiescent and Disable Currents**

Quiescent Current ( $I_q$ ) is the difference between the input current (measured through the LDO input pin) and the output load current.

**Current Limit and Short Circuit Current Limit**

Current Limit is value of output current by which output voltage drops below 96% of its nominal value. Short Circuit Current Limit is output current value measured with output of the regulator shorted to ground.

**PSRR**

Power Supply Rejection Ratio is defined as ratio of output voltage and input voltage ripple. It is measured in decibels (dB).

**Line Transient Response**

Typical output voltage overshoot and undershoot response when the input voltage is excited with a given slope.

**Load Transient Response**

Typical output voltage overshoot and undershoot response when the output current is excited with a given slope between low-load and high-load conditions.

**Thermal Protection**

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 175°C, the regulator turns off. This feature is provided to prevent failures from accidental overheating.

**Maximum Package Power Dissipation**

The power dissipation level is maximum allowed power dissipation for particular package or power dissipation at which the junction temperature reaches its maximum operating value, whichever is lower.

## APPLICATIONS INFORMATION

The NCV8774 regulator is self-protected with internal thermal shutdown and internal current limit. Typical characteristics are shown in Figures 4 to 26.

### Input Decoupling ( $C_{in}$ )

A ceramic or tantalum 0.1  $\mu$ F capacitor is recommended and should be connected close to the NCV8774 package. Higher capacitance and lower ESR will improve the overall line and load transient response.

If extremely fast input voltage transients are expected then appropriate input filter must be used in order to decrease rising and/or falling edges below 50 V/ $\mu$ s for proper operation. The filter can be composed of several capacitors in parallel.

### Output Decoupling ( $C_{out}$ )

The NCV8774 is a stable component and does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. Stability region of ESR vs Output Current is shown in Figure 17. The minimum output decoupling value is 1  $\mu$ F and can be augmented to fulfill stringent load transient requirements. The regulator works with ceramic chip capacitors as well as tantalum devices. Larger values improve noise rejection and load regulation transient response.

### Thermal Considerations

As power in the NCV8774 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. When the NCV8774 has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power applications. The maximum dissipation the NCV8774 can handle is given by:

$$P_{D(max)} = \frac{[T_{J(max)} - T_A]}{R_{\theta JA}} \quad (\text{eq. 1})$$

### ORDERING INFORMATION

| Device         | Output Voltage | Marking | Package             | Shipping†             |
|----------------|----------------|---------|---------------------|-----------------------|
| NCV8774DT50RKG | 5.0 V          | 877450G | DPAK-3<br>(Pb-Free) | 2500 /<br>Tape & Reel |
| NCV8774DT33RKG | 3.3 V          | 877433G | DPAK-3<br>(Pb-Free) | 2500 /<br>Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Since  $T_J$  is not recommended to exceed 150°C, then the NCV8774 soldered on 645 mm<sup>2</sup>, 1 oz copper area, FR4 can dissipate up to 2.35 W when the ambient temperature ( $T_A$ ) is 25°C. See Figure 27 for  $R_{\theta JA}$  versus PCB area. The power dissipated by the NCV8774 can be calculated from the following equations:

$$P_D = V_{in}(I_q @ I_{out}) + I_{out}(V_{in} - V_{out}) \quad (\text{eq. 2})$$

or

$$V_{in(max)} = \frac{P_{D(max)} + (V_{out} \times I_{out})}{I_{out} + I_q} \quad (\text{eq. 3})$$

NOTE: Items containing  $I_q$  can be neglected if  $I_{out} \gg I_q$ .

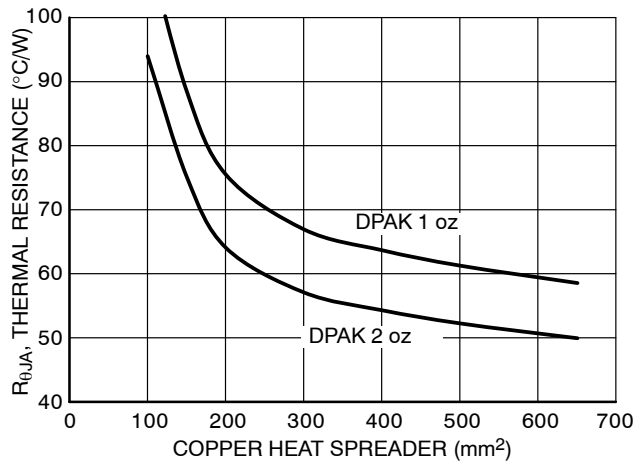
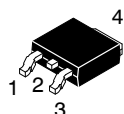


Figure 27. Thermal Resistance vs. PCB Copper Area

### Hints

$V_{in}$  and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCV8774 and make traces as short as possible.

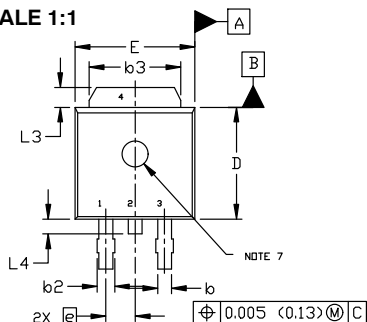
# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



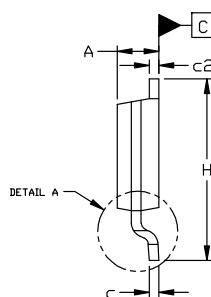
## DPAK (SINGLE GAUGE) CASE 369C ISSUE G

DATE 31 MAY 2023

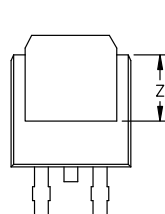
SCALE 1:1



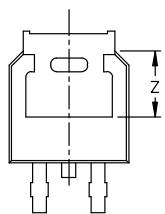
TOP VIEW



SIDE VIEW

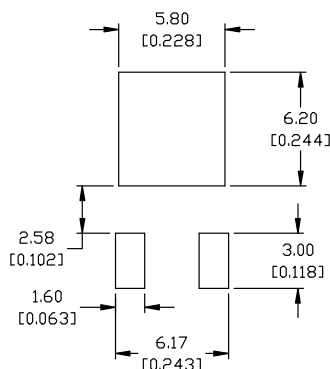


BOTTOM VIEW



BOTTOM VIEW

ALTERNATE  
CONSTRUCTIONS



### RECOMMENDED MOUNTING FOOTPRINT\*

\*FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D.

#### STYLE 1:

PIN 1. BASE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR

#### STYLE 2:

PIN 1. GATE  
2. DRAIN  
3. SOURCE  
4. DRAIN

#### STYLE 3:

PIN 1. ANODE  
2. CATHODE  
3. ANODE  
4. CATHODE

#### STYLE 4:

PIN 1. CATHODE  
2. ANODE  
3. GATE  
4. ANODE

#### STYLE 5:

PIN 1. GATE  
2. ANODE  
3. CATHODE  
4. ANODE

#### STYLE 6:

PIN 1. MT1  
2. MT2  
3. GATE  
4. MT2

#### STYLE 7:

PIN 1. GATE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR

#### STYLE 8:

PIN 1. N/C  
2. CATHODE  
3. ANODE  
4. CATHODE

#### STYLE 9:

PIN 1. ANODE  
2. CATHODE  
3. RESISTOR ADJUST  
4. CATHODE

#### STYLE 10:

PIN 1. CATHODE  
2. ANODE  
3. CATHODE  
4. ANODE

### NOTES:

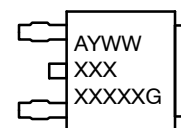
1. DIMENSIONING AND TOLERANCING ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3, AND Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. OPTIONAL MOLD FEATURE.

| DIM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN.   | MAX.  | MIN.        | MAX.  |
| A   | 0.086  | 0.094 | 2.18        | 2.38  |
| A1  | 0.000  | 0.005 | 0.00        | 0.13  |
| b   | 0.025  | 0.035 | 0.63        | 0.89  |
| b2  | 0.028  | 0.045 | 0.72        | 1.14  |
| b3  | 0.180  | 0.215 | 4.57        | 5.46  |
| c   | 0.018  | 0.024 | 0.46        | 0.61  |
| c2  | 0.018  | 0.024 | 0.46        | 0.61  |
| D   | 0.235  | 0.245 | 5.97        | 6.22  |
| E   | 0.250  | 0.265 | 6.35        | 6.73  |
| e   | 0.090  | BSC   | 2.29        | BSC   |
| H   | 0.370  | 0.410 | 9.40        | 10.41 |
| L   | 0.055  | 0.070 | 1.40        | 1.78  |
| L1  | 0.114  | REF   | 2.90        | REF   |
| L2  | 0.020  | BSC   | 0.51        | BSC   |
| L3  | 0.035  | 0.050 | 0.89        | 1.27  |
| L4  | ----   | 0.040 | ---         | 1.01  |
| Z   | 0.155  | ----  | 3.93        | ---   |

### GENERIC MARKING DIAGRAM\*



IC



Discrete

XXXXXX = Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

|                  |                     |                                                                                                                                                                                     |
|------------------|---------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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| DESCRIPTION:     | DPAK (SINGLE GAUGE) | PAGE 1 OF 1                                                                                                                                                                         |

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